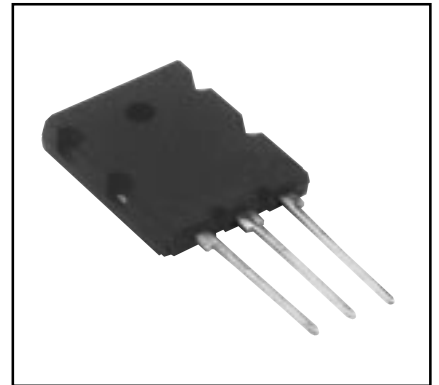
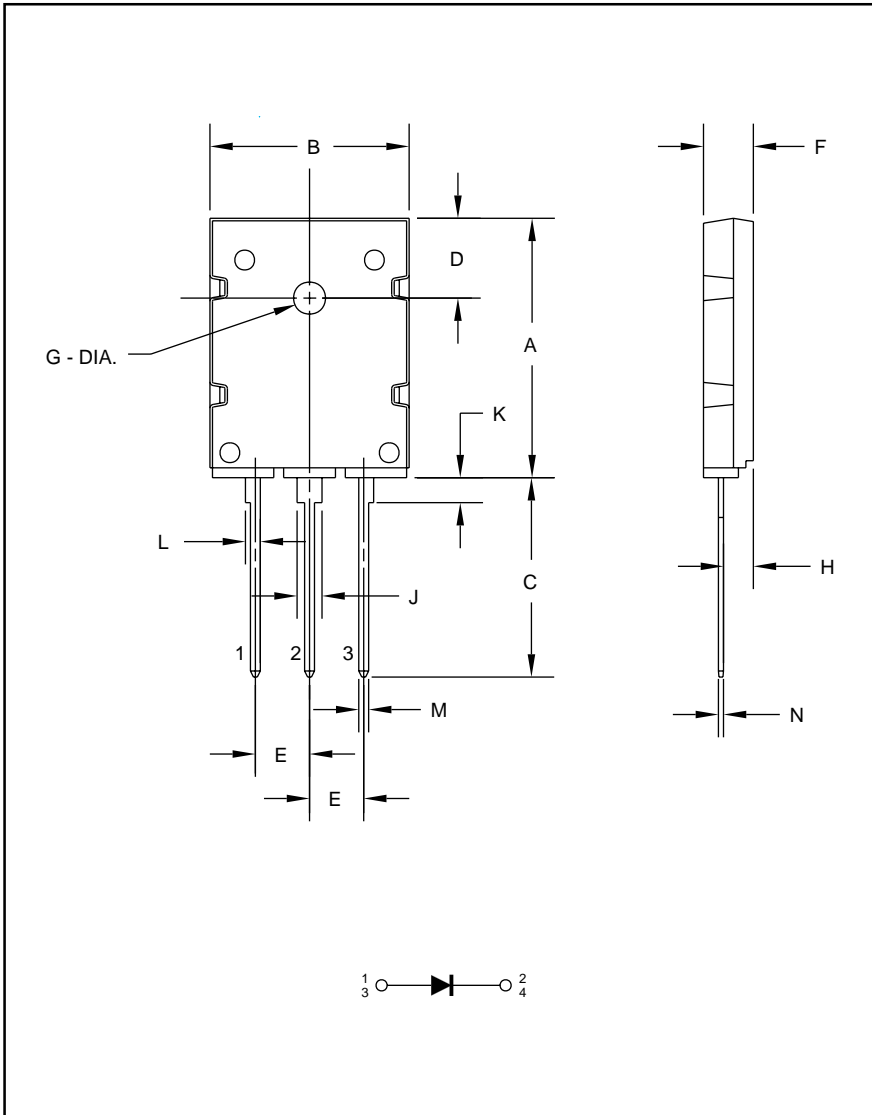


RM25HG-24S

HIGH SPEED SWITCHING USE
NON-INSULATED TYPE



Description:

Mitsubishi Super Fast Recovery Diodes are designed for use in applications requiring fast switching.

Features:

- Non-Isolated Package
- Planar Chips
- $t_{rr} = 300\text{ns Max.}$

Applications:

- Snubber Circuits

Ordering Information:

Example: Select the complete part number from the table below -i.e. RM25HG-24S is a 1200V, 25 Ampere Super Fast Recovery Single Diode Module.

Outline Drawing and Circuit Diagram

| Dimension | Inches | Millimeters |
|-----------|------------------|--------------|
| A | 1.102±0.02 | 26.0±0.5 |
| B | 0.81 Max. | 20.5 Max. |
| C | 0.79 Min. | 20.0 Min. |
| D | 0.24±0.008 | 6.0±0.2 |
| E | 0.214±0.012 | 5.45±0.3 |
| F | 0.20±0.012 | 5.0±0.3 |
| G | 0.214±0.012 Dia. | Dia. 3.2±0.2 |

| Dimension | Inches | Millimeters |
|-----------|------------|-------------|
| H | 0.12±0.012 | 3.0±0.3 |
| J | 0.10±0.012 | 2.5±0.3 |
| K | 0.10 | 2.5 |
| L | 0.08±0.012 | 2.0±0.3 |
| M | 0.04±0.008 | 1.0±0.2 |
| N | 0.02±0.008 | 0.6±0.2 |

| Type | Current Rating Amperes | Voltage Volts (x 50) |
|------|---------------------------|-------------------------|
| RM | 25 | 24 |

RM25HG-24S

HIGH SPEED SWITCHING USE
NON-INSULATED TYPE

Absolute Maximum Ratings, $T_j = 25^\circ\text{C}$ unless otherwise specified

| Ratings | Symbol | RM25HG-24S | Units |
|--|-------------|-------------|------------------|
| Peak Reverse Blocking Voltage (Repetitive) | V_{RRM} | 1200 | Volts |
| Peak Reverse Blocking Voltage (Non-Repetitive) | V_{RSM} | 1350 | Volts |
| DC Reverse Blocking Voltage | $V_{R(DC)}$ | 960 | Volts |
| DC Current, $T_C = 80^\circ\text{C}$ (Resistive Load) | $I_{F(DC)}$ | 25 | Amperes |
| Peak Half-Cycle Surge (Non-Repetitive) On-State Current (60Hz) | I_{FSM} | 500 | Amperes |
| Storage Temperature | T_{stg} | -40 to +125 | $^\circ\text{C}$ |
| Operating Temperature | T_j | -40 to +150 | $^\circ\text{C}$ |
| Maximum Mounting Torque M3 Mounting Screw | — | 0.59–0.98 | N · m |
| Module Weight (Typical) | — | 10 | Grams |

Electrical and Thermal Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

| Characteristics | Symbol | Test Conditions | Max. | Units |
|-------------------------------------|---------------|---|------|------------------------------|
| Blocking State Maximums | | | | |
| Reverse Leakage Current, Peak | I_{RRM} | V_{RRM} applied, $T_j = 25^\circ\text{C}$ | 0.1 | mA |
| | | V_{RRM} applied, $T_j = 125^\circ\text{C}$ | 1.0 | mA |
| Conducting State Maximums | | | | |
| Forward Voltage Drop | V_{FM} | $T_j = 25^\circ\text{C}$, $I_{FM} = 100\text{A}$ | 4.0 | Volts |
| Switching Minimums | | | | |
| Reverse Recovery Time | t_{rr} | $T_j = 25^\circ\text{C}$, $I_{FM} = 100\text{A}$ $di/dt = -500\text{A}/\mu\text{s}$, $V_R = 600\text{V}$ | 0.3 | μs |
| Lead Integrity | | | | |
| | — | Tension Load: 2.5 kg | 30.0 | s |
| | — | Bending Load: 1 kg bent to 90° | 2.0 | times |
| Thermal Maximums | | | | |
| Junction to Case Thermal Resistance | $R_{th(j-c)}$ | Junction to case | 0.5 | $^\circ\text{C}/\text{Watt}$ |
| Contact Thermal Resistance | $R_{th(c-f)}$ | Case to Fin, Thermal Grease Applied | 0.5 | $^\circ\text{C}/\text{Watt}$ |

*Maximum ratings unless otherwise specified

